

# MMBT5401M3

## High Voltage Transistor

### PNP Silicon

The MMBT5401M3 device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-150	Vdc
Collector - Base Voltage	$V_{CBO}$	-160	Vdc
Emitter - Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current - Continuous	$I_C$	-60	mA <sub>dc</sub>

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	130	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	470	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-5 @ 100 mm<sup>2</sup>, 1.0 oz. copper traces, still air.

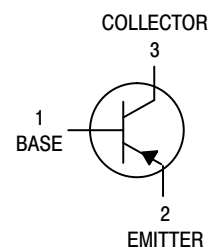


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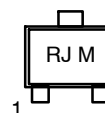
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SOT-723  
CASE 631AA



#### MARKING DIAGRAM



RJ = Specific Device Code  
M = Date Code

#### ORDERING INFORMATION

Device	Package	Shipping†
MMBT5401M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSVMMBT5401M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBT5401M3

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ( $I_C = -1.0\text{ mA}$ , $I_B = 0$ )	$V_{(BR)CEO}$	-150	–	–	V
Collector–Base Breakdown Voltage ( $I_C = -100\ \mu\text{A}$ , $I_E = 0$ )	$V_{(BR)CBO}$	-160	–	–	V
Emitter–Base Breakdown Voltage ( $I_E = -10\ \mu\text{A}$ , $I_C = 0$ )	$V_{(BR)EBO}$	-5.0	–	–	V
Collector–Base Cutoff Current ( $V_{CB} = -120\text{ V}$ , $I_E = 0$ )	$I_{CBO}$	–	-1.6	-100	nA
Emitter Cutoff Current ( $V_{BE} = -5\text{ V}$ )	$I_{EBO}$	–	-0.20	-100	nA

### ON CHARACTERISTICS

DC Current Gain ( $I_C = -1.0\text{ mA}$ , $V_{CE} = -5.0\text{ V}$ ) ( $I_C = -10\text{ mA}$ , $V_{CE} = -5.0\text{ V}$ ) ( $I_C = -50\text{ mA}$ , $V_{CE} = -5.0\text{ V}$ )	$h_{FE}$	50 60 20	80 90 40	– 240 –	–
Collector–Emitter Saturation Voltage ( $I_C = -10\text{ mA}$ , $I_B = -1.0\text{ mA}$ ) ( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )	$V_{CE(sat)}$	– –	-0.09 -0.15	-0.25 -0.60	V
Base–Emitter Saturation Voltage ( $I_C = -10\text{ mA}$ , $I_B = -1.0\text{ mA}$ ) ( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )	$V_{BE(sat)}$	– –	-0.76 -0.92	-1.0 -1.0	V

### SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ( $I_C = -10\text{ mA}$ , $V_{CE} = -5.0\text{ V}$ , $f = 100\text{ MHz}$ )	$f_T$	100	180	300	MHz
Input Capacitance ( $V_{EB} = -3\text{ V}$ , $I_C = 0$ , $f = 1.0\text{ MHz}$ )	$C_{ibo}$	–	12.5	15	pF
Output Capacitance ( $V_{CB} = -10\text{ V}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )	$C_{obo}$	–	1.5	6.0	pF
Small Signal Current Gain ( $I_C = -1.0\text{ mA}$ , $V_{CE} = -10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	40	–	200	–
Noise Figure ( $I_C = -200\ \mu\text{A}$ , $V_{CE} = -5.0\text{ V}$ , $R_S = 10\ \Omega$ , $f = 1.0\text{ kHz}$ )	NF	–	–	8.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

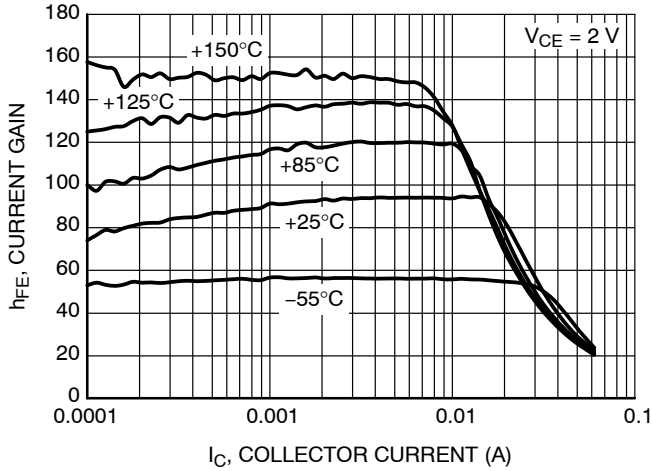


Figure 1. DC Current Gain

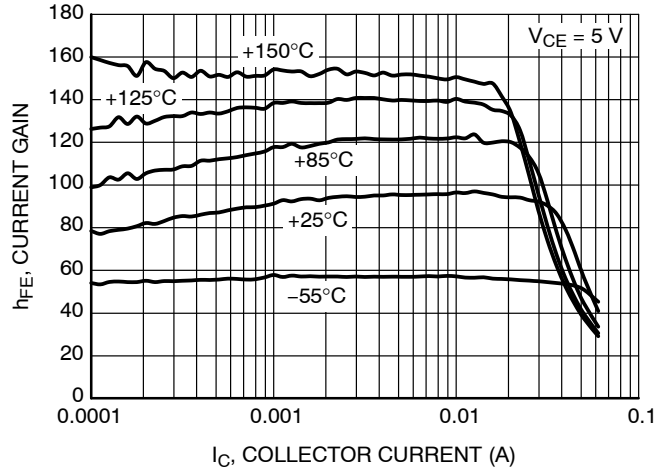


Figure 2. DC Current Gain

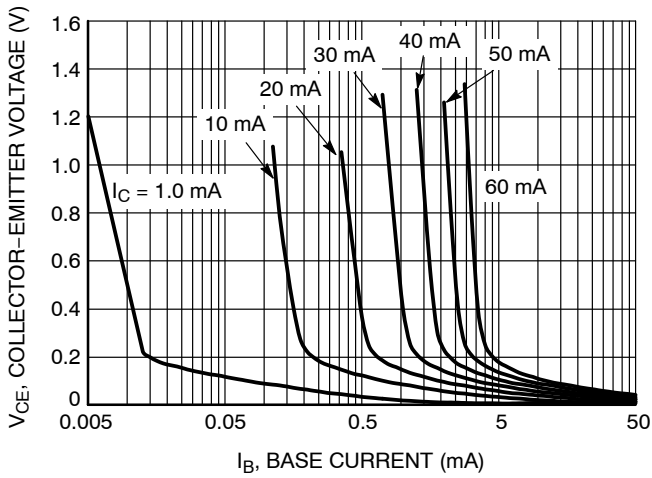


Figure 3. Collector Saturation Region

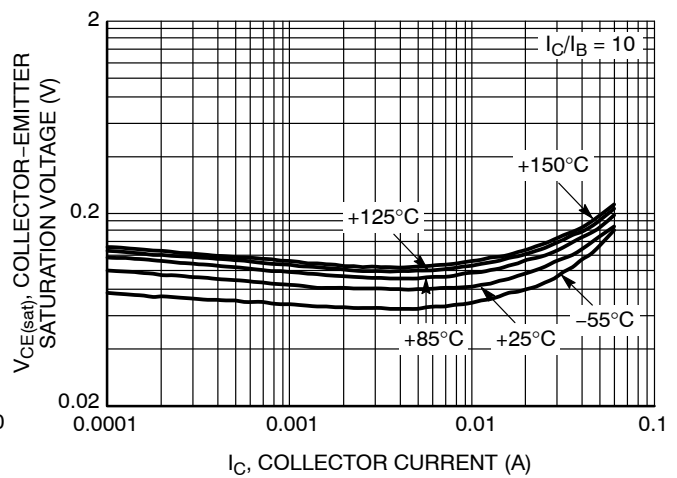


Figure 4. Collector-Emitter Saturation Region

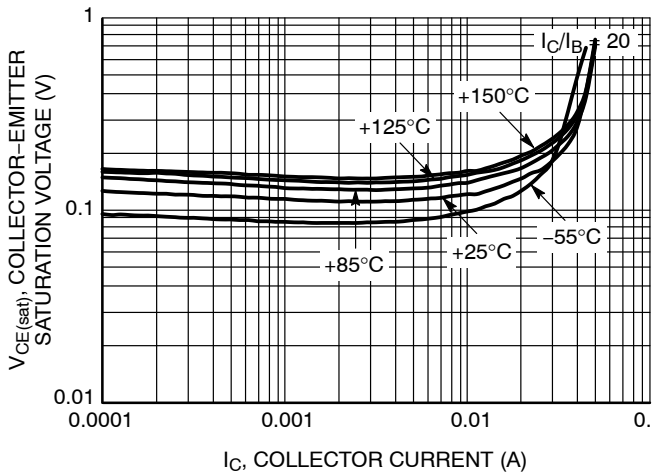


Figure 5. Collector-Emitter Saturation Region

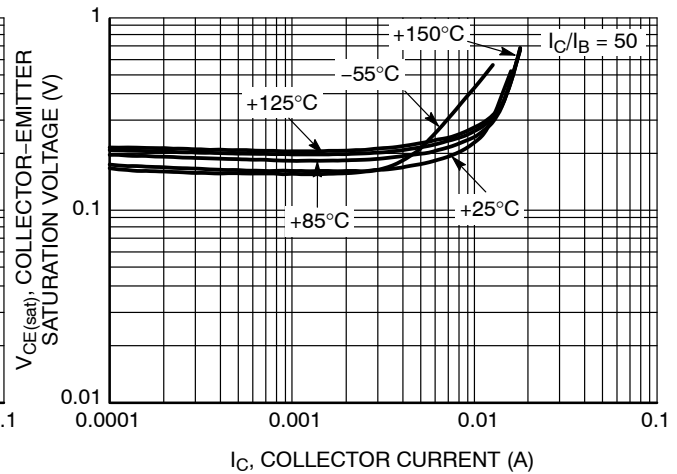


Figure 6. Collector-Emitter Saturation Region

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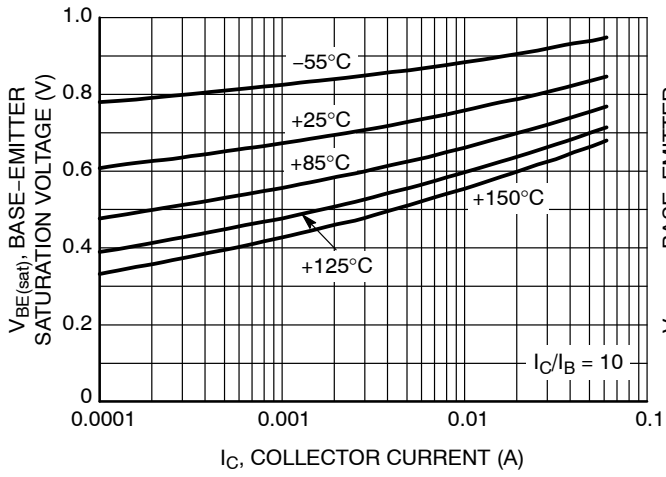


Figure 7. Base-Emitter Saturation Voltage

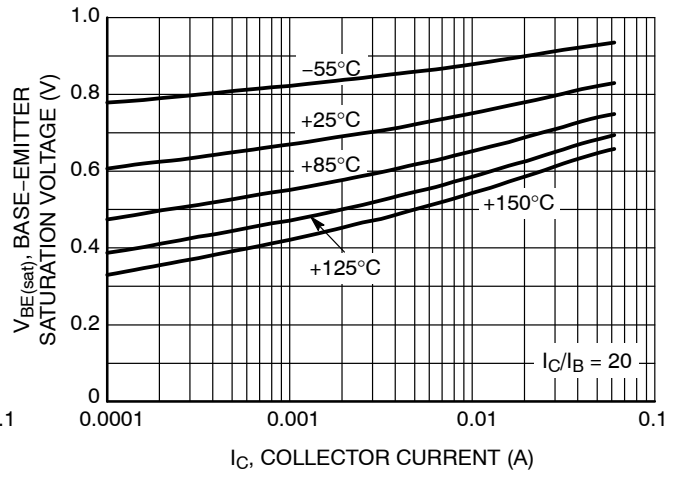


Figure 8. Base-Emitter Saturation Voltage

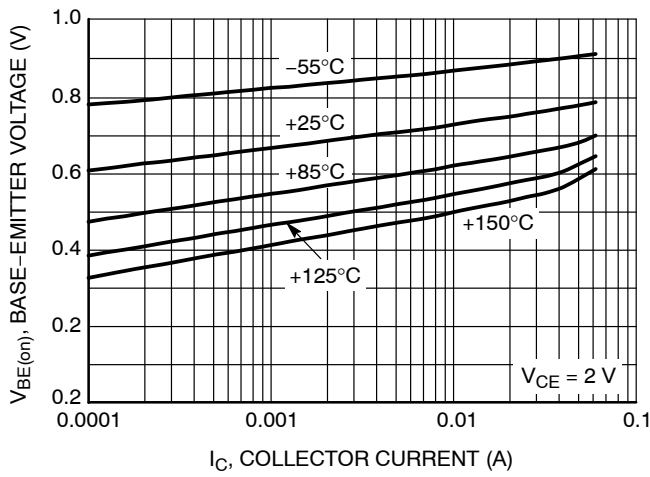


Figure 9. Base-Emitter "ON" Voltage

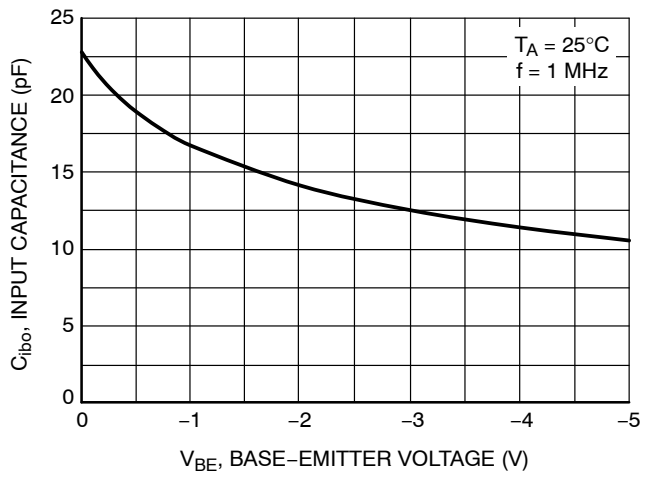


Figure 10. Input Capacitance

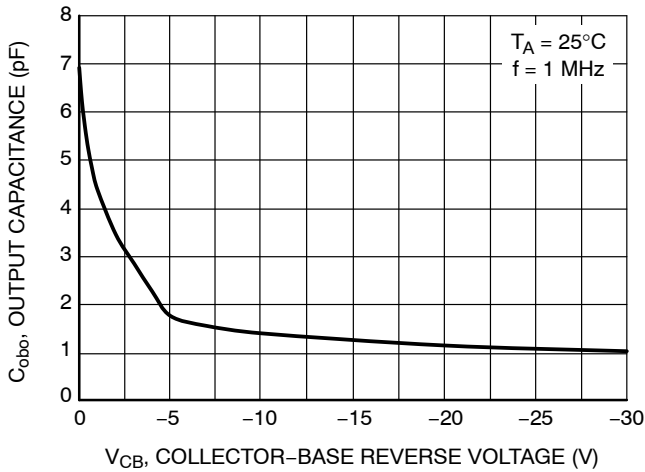


Figure 11. Output Capacitance

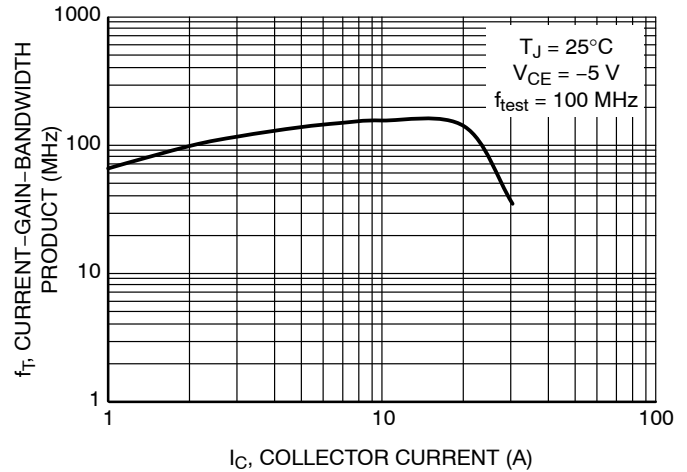


Figure 12. Current Gain Bandwidth Product

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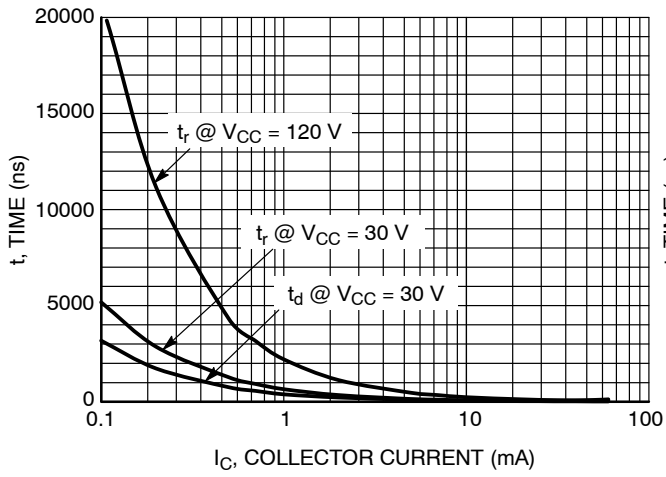


Figure 13. Turn-On Time

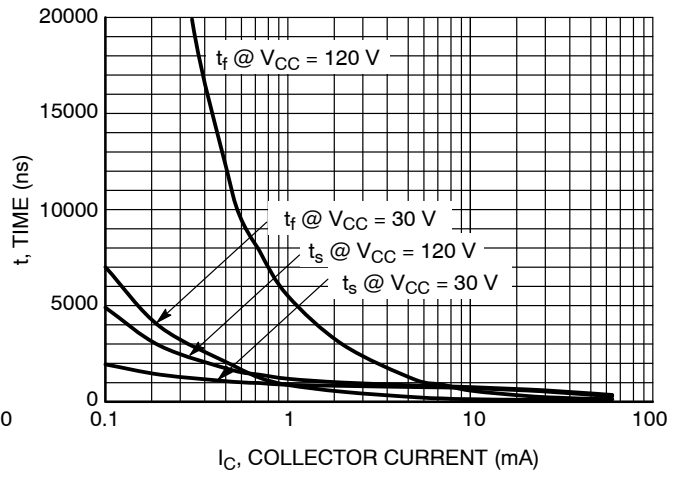
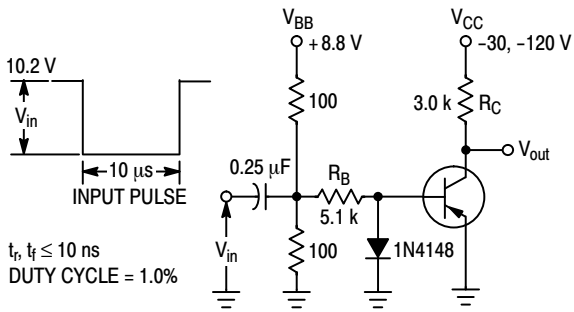


Figure 14. Turn-Off Time



$t_r, t_f \leq 10 \text{ ns}$   
DUTY CYCLE = 1.0%

Values Shown are for  $I_C @ 10 \text{ mA}$

Figure 15. Switching Time Test Circuit

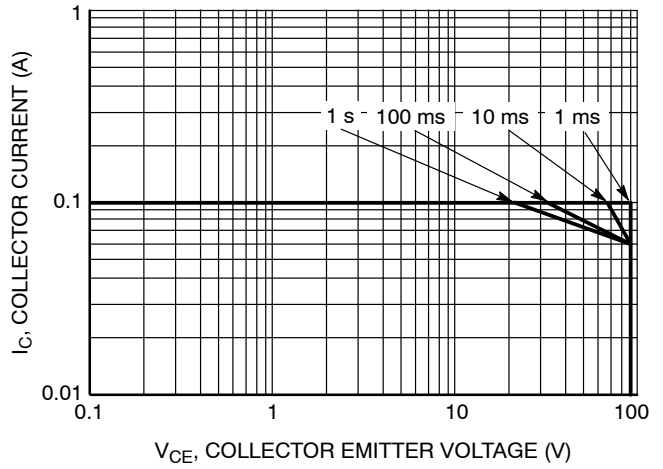
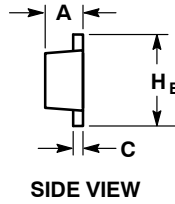
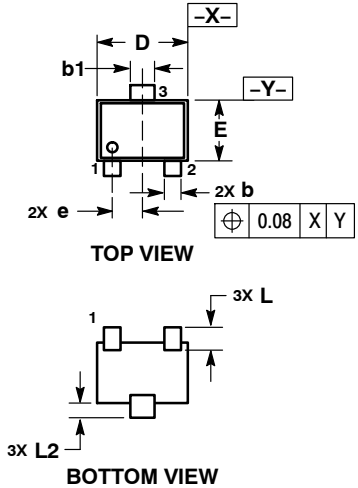


Figure 16. Safe Operating Area

# MMBT5401M3

## PACKAGE DIMENSIONS

SOT-723  
CASE 631AA  
ISSUE D

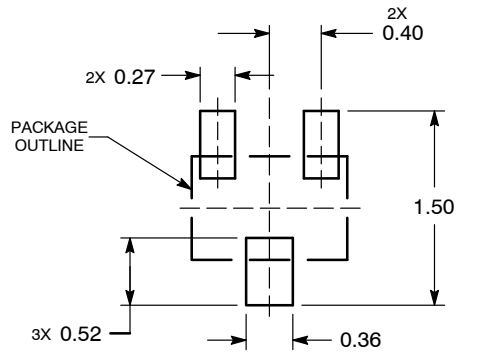


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.45	0.50	0.55
b	0.15	0.21	0.27
b1	0.25	0.31	0.37
C	0.07	0.12	0.17
D	1.15	1.20	1.25
E	0.75	0.80	0.85
e	0.40 BSC		
H E	1.15	1.20	1.25
L	0.29 REF		
L2	0.15	0.20	0.25

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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